



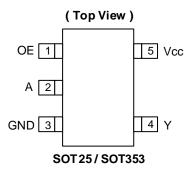


SINGLE BUFFER GATE WITH 3-STATE OUTPUT

Description

The 74AHCT1G126Q is an automotive compliant, single non-inverting buffer/bus driver with a 3-state output. The output enters a high impedance state when a LOW-level is applied to the output enable (OE) pin. The device is designed for operation with a power supply range of 4.5V to 5.5V.

Pin Assignments



Features

- Grade 1 Ambient Temperature Operation: -40°C to +125°C
- Supply Voltage Range from 4.5V to 5.5V
- ±8mA Output Drive at 5.0V
- CMOS Low-Power Consumption
- Schmitt Trigger Action at All Inputs Make the Circuit Tolerant for Slower Input Rise and Fall Time
- Inputs Not Limited by Vcc
- Balanced Propagation Delays
- Balanced Drive Capability
- ESD Protection Tested per AEC-Q100
- Exceeds 2000-V Human Body Model (AEC-Q100-002)
- Exceeds 1000-V Charged Device Model (AEC-Q100-011)
- Latch-Up Exceeds 100mA (AEC-Q100-004)
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- The 74AHCT1G126Q is suitable for automotive applications requiring specific change control; this part is AEC-Q100 qualified, PPAP capable, and manufactured in IATF 16949 certified facilities.

https://www.diodes.com/quality/product-definitions/

Applications

- General Purpose Logic
- Wide Array of Products, such as:
 - Automotive Applications within Grade 1 Temperature Range
 - Industrial Computing/Controls/Automation
 - High Reliability Networking/Communications
 - Industrial/Agricultural Equipment

Notes:

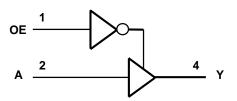
- 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant.
- 2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.



Pin Descriptions

Pin Name	Description			
OE	Output Enable Active HIGH			
Α	Data Input			
GND	Ground			
Υ	Data Output			
Vcc	Supply Voltage			

Logic Diagram



Function Table

Inp	Output	
OE	Α	Y
Н	Н	Н
Н	L	L
L	Х	Z

Absolute Maximum Ratings (Notes 4 & 5)

Symbol	Description	Rating	Unit
ESD HBM	Human Body Model ESD Protection	2	kV
ESD CDM	Charged Device Model ESD Protection	1	kV
Vcc	Supply Voltage Range	-0.5 to 6.5	V
Vı	Input Voltage Range	-0.5 to 6.5	V
Vo	Voltage Applied to Output in High or Low State	-0.5 to Vcc + 0.5	V
lıĸ	Input Clamp Current V _I < 0	-20	mA
lok	Output Clamp Current (Vo < 0 or Vo > Vcc)	±20	mA
lo	Continuous Output Current (V _O = 0 to V _{CC})	±25	mA
Icc	Continuous Current Through V _{CC}	75	mA
I _{GND}	Continuous Current Through GND	-75	mA
TJ	Operating Junction Temperature	-40 to +150	°C
Tstg	Storage Temperature	-65 to +150	°C
PD	Total Power Dissipation (Note 6)	250	mW

Notes:

- 4. Stresses beyond the absolute maximum can result in immediate failure or reduced reliability. These are stress values and device operation should be within recommend values.
- 5. Forcing the maximum allowed voltage could cause a condition exceeding the maximum current or conversely forcing the maximum current could cause a condition exceeding the maximum voltage. The ratings of both current and voltage must be maintained within the controlled range.
- 6. This will need to be derated at higher operating temperatures to prevent exceeding maximum T_J. Refer to package thermal characteristics section.



Recommended Operating Conditions (Note 7)

Symbol	Pai	rameter	Min	Max	Unit
Vcc	Operating Voltage	_	4.5	5.5	V
V _{IH}	High-Level Input Voltage	$V_{CC} = 5V \pm 0.5V$	2.0		V
VIL	Low-Level Input Voltage	$V_{CC} = 5V \pm 0.5V$	_	0.8	V
Vı	Input Voltage		0	5.5	V
Vo	Output Voltage		0	Vcc	V
Іон	High-Level Output Current	$V_{CC} = 5V \pm 0.5V$	_	-8	mA
loL	Low-Level Output Current	$V_{CC} = 5V \pm 0.5V$	_	8	mA
Δt/ΔV	Input Transition Rise or Fall Rate	$V_{CC} = 5V \pm 0.5V$	_	20	ns/V
TA	Ambient Temperature	_	-40	+125	°C

Note:

Electrical Characteristics (All typical values are at Vcc = 3.3V, TA = +25°C.)

0	B	Tank Oan didaya	.,		+25°C		-40°C to	o +85°C	-40°C to	+125°C	11!4
Symbol	Parameter	Test Conditions	Vcc	Min	Тур	Max	Min	Max	Min	Max	Unit
	High Level Output	V _I = V _{IH} or V _{IL} I _{OH} = -50µA	4.5V	4.4	4.5	_	4.4	_	4.4		V
Vон	Voltage	V _I = V _{IH} or V _{IL} I _{OH} = -8mA	4.5V	3.94			3.8	1	3.70	-	V
.,	Low Level Output	VI = VIH or VIL IOL = 50µA	4.5V	1	0	0.1	-	0.1	_	0.1	V
V _{OL} Voltage	V _I = V _{IH} or V _{IL} I _{OL} = 8mA	4.5V		_	0.36	_	0.44	_	0.55	V	
loz	Z State Leakage Current	$V_I = 5.5V$ or GND $V_O = 0$ to 5.5V	5.5V	1	_	0.25	1	2.5	_	10	μΑ
II	Input Current	V _I = 5.5V or GND	0 to 5.5V	_	_	±0.1	_	±1	_	±2	μΑ
ΔΙσο	Additional Supply Current	Per input pin; $V_I = 3.4V$; other inputs at V_{CC} or GND; $I_O = 0$	5.5V		_	1.35	-	1.5	_	1.5	mA
Icc	Supply Current	$V_I = 5.5V$ or GND $I_O = 0$	5.5V	_	_	1	_	10	_	40	μΑ
Cı	Input Capacitance	$V_I = V_{CC}$ or GND	5.5V		1.5	10		10	_	10	pF

^{7.} Unused inputs should be held at $V_{\mbox{\footnotesize CC}}$ or Ground.



Package Characteristics

Symbol	Parameter	Package	Test Conditions	Min	Тур	Max	Unit
0	Thermal Resistance	SOT25	Note 0	_	184	_	90044
ALθ	Junction-to-Ambient	SOT353	Note 8	_	385	_	°C/W
0	Thermal Resistance	SOT25	Nata 0	_	62	_	0000
θЈС	Junction-to-Case	SOT353	Note 8	_	164	_	°C/W

Note: 8. Device mounted on FR-4 substrate PC board, 2oz copper, with minimum recommended pad layout.

Switching Characteristics

 $Vcc = 5V \pm 0.5V$ (See Figure 1, Typical values at Vcc = 5V.)

Dozomotoz	From	То	Test		+25°C		-40°C to +85°C		-40°C to	Unit	
Parameter	(Input)	(Output)	Conditions	Min	Тур	Max	Min	Max	Min	Max	Unit
4	Λ	V	C _L = 15pF	1.0	3.4	5.5	1.0	6.5	1.0	7.0	ns
tpD	Α	Ť	C _L = 50pF	1.0	4.8	7.5	1.0	8.5	1.0	9.5	ns
4	OE	V	$C_L = 15pF$	1.0	3.9	5.1	1.0	6.0	1.0	6.5	ns
ten	OE	Ť	C _L = 50pF	1.0	5.1	7.5	1.0	9.0	1.0	9.5	ns
4	OE	V	C _L = 15pF	1.0	4.5	6.8	1.0	8.0	1.0	8.5	ns
t _{DIS}	OE	Ť	C _L = 50pF	1.0	6.1	8.8	1.0	10.0	1.0	11.0	ns

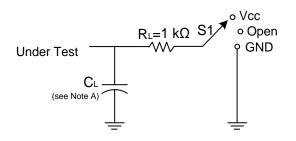
Operating Characteristics

 $T_A = +25$ °C

	Parameter	Test Conditions	Тур	Unit
C _{PD}	Power Dissipation Capacitance	$V_{CC} = 5.0V, f = 1MHz$ $C_L = 50pF$ $V_I = GND to V_{CC}$	11	pF

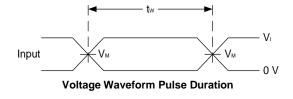


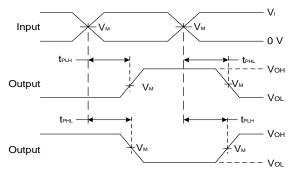
Measurement Information



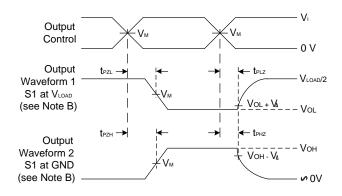
Test	S1
tplH/tpHL	Open
tplz/tpzl	VLOAD
t _{PHZ} /t _{PZH}	GND

V	Inp	uts	Voc	W	6:	D.	V/A
Vcc	Vı	t _R /t _F	Vм	VLOAD	C∟	R∟	V Δ
5V±0.5V	GND to 3V	≤2.5ns	1.5V	Vcc	15pF	1kΩ	0.3V
5V±0.5V	GND to 3V	≤2.5ns	1.5V	Vcc	50pF	1kΩ	0.3V





Voltage Waveform Propagation Delay Times Inverting and Non Inverting Outputs



Voltage Waveform Enable and Disable Times Low and High Level Enabling

Figure 1. Load Circuit and Voltage Waveforms

Notes: A. Includes test lead and test apparatus capacitance.

B. All pulses are supplied at pulse repetition rate ≤ 1MHz.

C. Inputs are measured separately one transition per measurement.

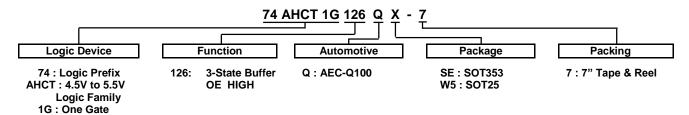
D. t_{PLZ} and t_{PHZ} are the same as t_{DIS}.

E. t_{PZL} and t_{PZH} are the same as $t_{\text{EN.}}$

F. t_{PLH} and t_{PHL} are the same as t_{PD}.



Ordering Information (Note 9)



Part Number	Package	Package	Package Size	7" Tape	and Reel
Fait Number	Code	(Notes 10 & 11)	Fackage Size	Quantity	Part Number Suffix
74AHCT1G126QSE-7	SE	SOT353	2.15 mm \times 2.1 mm \times 1.1 mm 0.65 mm lead pitch	3000/Tape & Reel	-7
74AHCT1G126QW5-7	W5	SOT25	3.0 mm \times 2.8 mm \times 1.2 mm 0.95 mm lead pitch	3000/Tape & Reel	-7

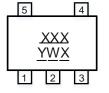
Notes: 9. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/.

10. Pad layout as shown in Diodes Incorporated's package outline PDFs, which can be found on our website at http://www.diodes.com/package-outlines.html.

11. The taping orientation is located on our website at https://www.diodes.com/assets/Packaging-Support-Docs/ap02007.pdf.

Marking Information

(Top View)



XXX : Identification Code Y : Year 0~9

Week: A~Z 1~26 week

a~z 27~52 week z represents week 52 and 53

X : A~ Z: Internal Code

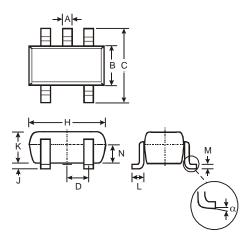
SOT25 / SOT353

Part Number	Package	Identification Code
74AHCT1G126QW5-7	SOT25	ZZQ
74AHCT1G126QSE-7	SOT353	ZZQ



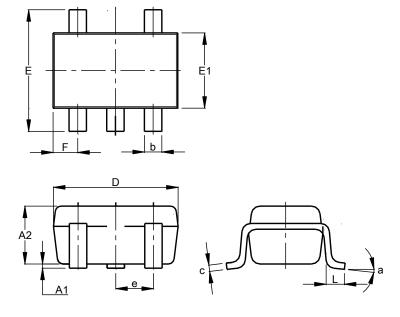
Package Outline Dimensions

(1) Package Type: SOT25



SOT25					
Dim	Min	Max	Тур		
Α	0.35	0.50	0.38		
В	1.50	1.70	1.60		
С	2.70	3.00	2.80		
D	-	1	0.95		
Н	2.90	3.10	3.00		
J	0.013	0.10	0.05		
K	1.00	1.30	1.10		
L	0.35	0.55	0.40		
M	0.10	0.20	0.15		
N	0.70	0.80	0.75		
α	0°	8°	-		
All Dimensions in mm					

(2) Package Type: SOT353



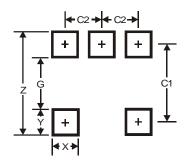
SOT353					
Dim	Min	Max	Тур		
A1	0.00	0.10	0.05		
A2	0.90	1.00	0.95		
b	0.10	0.30	0.25		
С	0.10	0.22	0.11		
D	1.80	2.20	2.15		
Е	2.00	2.20	2.10		
E1	1.15	1.35	1.30		
е	0.650 BSC				
F	0.40	0.45	0.425		
L	0.25	0.40	0.30		
а	0°	8°			
All Dimensions in mm					



Suggested Pad Layout

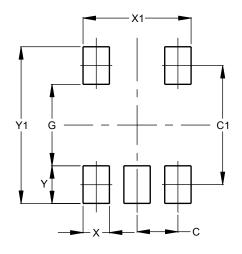
Please see http://www.diodes.com/package-outlines.html for the latest version.

(1) Package Type: SOT25



Dimensions	Value	
Z	3.20	
G	1.60	
Х	0.55	
Υ	0.80	
C1	2.40	
C2	0.95	

(2) Package Type: SOT353



Dimensions	Value (in mm)
С	0.650
C1	1.900
G	1.300
Х	0.420
X1	1.720
Υ	0.600
Y1	2.500

Mechanical Data

SOT25

- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish Matte Tin Plated Leads, Solderable per MIL-STD-202, Method 208@3
- Weight: 0.0158 grams (Approximate)

SOT353

- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish Matte Tin Plated Leads, Solderable per MIL-STD-202, Method 208 (3)
- Weight: 0.0064 grams (Approximate)



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RHRXH162244K1 74AUP1G34FW5-7 74AUP1G07FW5-7 74LVC1G126FW4-7 74LVC2G126RA3-7 NLX2G17CMUTCG
74LVCE1G125FZ4-7 Le87501NQC 74AUP1G126FW5-7 TC74HC4050AP(F) 74LVCE1G07FZ4-7 NLX3G16DMUTCG
NLX2G06AMUTCG NLVVHC1G50DFT2G LE87100NQC LE87100NQCT LE87290YQC LE87290YQCT LE87511NQC LE87511NQCT
LE87557NQC LE87557NQCT LE87614MQC LE87614MQCT 74AUP1G125FW5-7 NLU2G16CMUTCG MC74LCX244MN2TWG